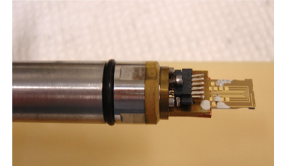


POSTDOC POSITION AT THE *UNIVERSITY OF PENNSYLVANIA* Department of Materials Science and Engineering

Seeking a postdoctoral fellow in the area of;

Nanowire Phase Change Memory-*in situ* TEM studies of the phase change process.

The project would involve studying nanoscale phase transitions in confined geometries via *in situ* electron microscopy studies to observe the critical processes that lead to field-induced phase change phenomena. Using chemical composition and size-controlled nanowires, structural phase transitions will be studied. The scope of this project involves nanowire growth, characterization, device fabrication, electrical measurements, *in situ* electron microscopy and theory/simulations. Candidates with PhD in any area of science and engineering can apply. However, people with a strong background in phase change memory devices and other device related areas will be preferred.



Please contact via email (riteshag@seas.upenn.edu) with a copy of your resume.

Key References:

- Y. Jung, S.W. Nam, and R. Agarwal, “High Resolution Transmission Electron Microscopy Study of Electrically-Driven Phase Change Phenomena in $\text{Ge}_2\text{Sb}_2\text{Te}_5$ Nanowires”, *Nano Letters*, 11, 1364 (2011).
- M. Mitra, Y. Jung, and R. Agarwal, “Extremely Low Drift of Resistance and Threshold Voltage in Amorphous Phase Change Nanowire Devices”, *Applied Physics Letters*, 96, 222111 (2010)
- Y. Jung, C.-Y. Yang, S.-H. Lee and R. Agarwal, “Phase-Change Ge-Sb Nanowires: Synthesis, Memory Switching, and Phase-Instability”, *Nano Letters*, 9, 2013 (2009).
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- S.-H. Lee, Y. Jung and R. Agarwal, “Highly-scalable nonvolatile and ultra-low power phase-change nanowire memory”, *Nature Nanotechnology*, 2, 626 (2007).